



BAS40V

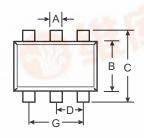
DUAL SURFACE MOUNT SCHOTTKY BARRIER DIODE

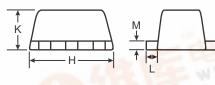
Features

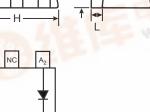
- Low Forward Voltage Drop
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 4)

Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Last Page
- Ordering Information: See Last Page
- Weight: 0.003 grams (approx.)







SOT-563									
Dim	Min	Max	Тур						
Α	0.15	0.30	0.25						
В	1.10	1.25	1.20						
С	1.55	1.70	1.60						
D	0.50								
G	0.90	1.10	1.00						
Н	1.50	1.70	1.60						
K	0.56	0.60	0.60						
L	0.10	0.30	0.20						
M	0.10	0.18	0.11						
All Dimensions in mm									

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Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit		
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	٧		
Forward Continuous Current (Note 2)	I _{FM}	200	mA		
Forward Surge Current (Note 2) @ t < 1.0s	I _{FSM}	600	mA		
Operating Temperature Range	Tj	-55 to +125	°C		
Storage Temperature Range	T _{STG}	-65 to +150	°C		

Thermal Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 2)	P _d	150	mW	
Thermal Resistance, Junction to Ambient Air (Note 2)	R ₀ JA	833	°C/W	

Electrical Characteristics @ TA = 25°C unless otherwise specified

Characteristic		Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 3)	V _{(BR)R}	40	_	_	V	$I_R = 10\mu A$
Forward Voltage	V _F	_	_	380 1000	mV	$t_{p} < 300 \mu s, I_{F} = 1.0 mA$ $t_{p} < 300 \mu s, I_{F} = 40 mA$
Reverse Leakage Current (Note 3)	I _R	_	20	200	nA	$t_p < 300 \mu s, V_R = 30 V$
Total Capacitance	C _T	_	4.0	5.0	pF	$V_R = 0V$, $f = 1.0MHz$
Reverse Recovery Time	t _{rr}	_	_	5.0	ns	$I_F = I_R = 10$ mA to $I_R = 1.0$ mA, $R_L = 100\Omega$

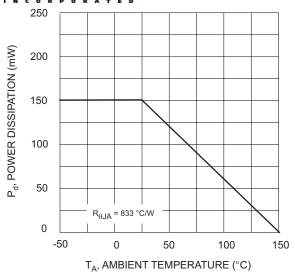
No purposefully added lead.

Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

5. Short duration test pulse used to minimize self-heating effect.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.





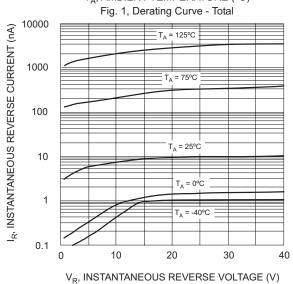
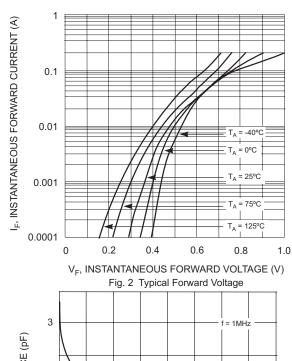
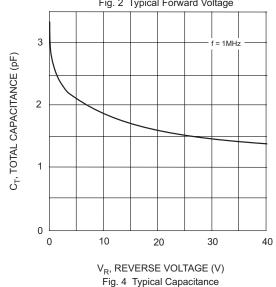


Fig. 3 Typical Reverse Characteristics





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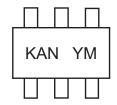
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Ordering Information (Note 4)

Device	Packaging	Shipping		
BAS40V-7	SOT-563	3000/Tape & Reel		

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



KAN = Product Type Marking Code YM = Date Code Marking Y = Year (ex: R = 2004) M = Month ex: 9 = September

Date Code Key

Code

Year		2004	2	005	2006	2007	2008	2009	20	10	2011	2012
Code		R		S	Т	U	V	W)	<	Υ	Z
Month	Jan	Feb	March	Apr	May	/ Jun	Jul	Aug	Sep	Oct	Nov	Dec

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